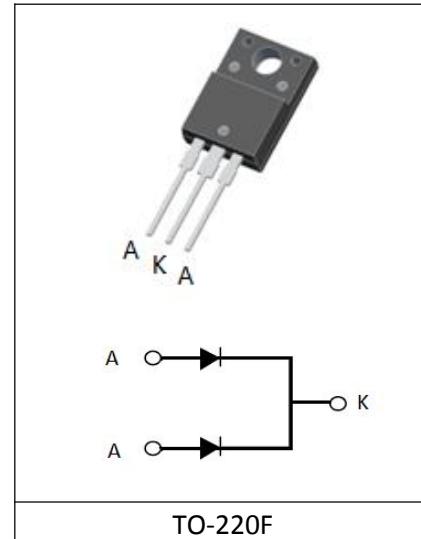


## SCHOTTKY RECTIFIERS

**Features:**

- Low power loss,high efficiency
- High surge capacity
- For use in low voltage,high frequency inverters, free wheeling, and polarity protection applications
- Metal silicon junction,majority carrier conduction
- Guard ring for over voltage protection

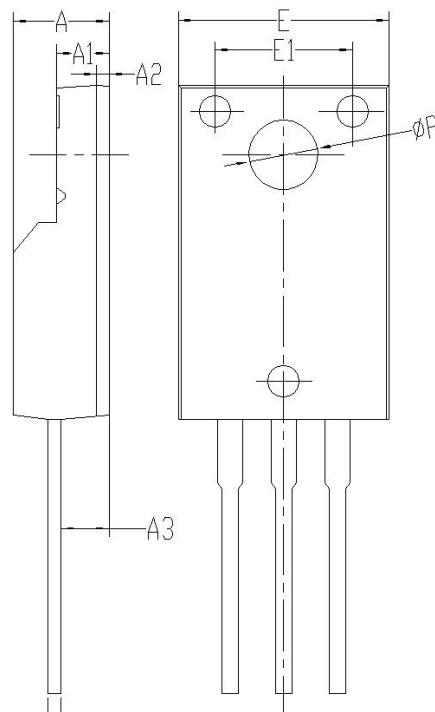
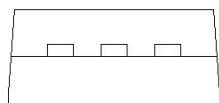
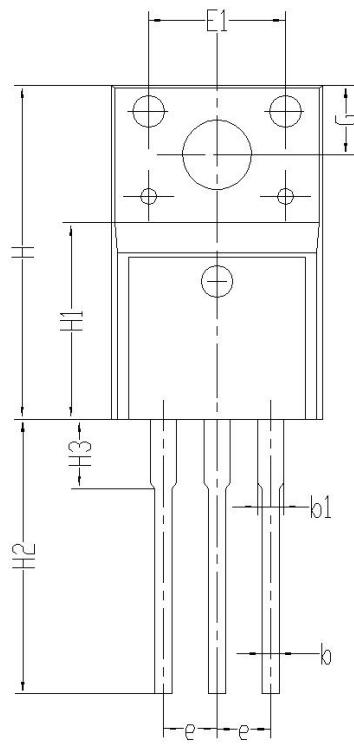

**Absolute Maximum Ratings(Tc=25°C):**

Characteristics		Symbol	Rating	Unit
Maximum Repetitive Reverse Voltage		V <sub>RRM</sub>	100	V
Average Rectified Forward Current		I <sub>F(AV)</sub>	20	A
Non-repetitive Peak Forward Surge Current 8.3ms Single Half-Sine-Wave		I <sub>FSM</sub>	135	A
Collector power dissipation	T <sub>a</sub> =25°C	P <sub>tot</sub>	2.0	W
Junction temperature		T <sub>j</sub>	175	°C
Storage temperature range		T <sub>STG</sub>	-55~175	°C

**Electrical Characteristics(Tc=25°C) :**

Characteristics	Symbol	Test Condition	Min	Typ	Max	Unit
Forward Voltage	V <sub>F</sub>	I <sub>F</sub> =10A; T <sub>c</sub> =25°C		0.8	0.9	V
Reverse Current	I <sub>R</sub>	V <sub>R</sub> =100V; T <sub>c</sub> =25°C V <sub>R</sub> =100V; T <sub>c</sub> =125°C			0.01 10.0	mA
Peak Repetitive Reverse Surge Current	I <sub>RRM</sub>	2.0 us Pulse Width ,f=1.0KHZ T <sub>j</sub> <175°C			5	A

Symbol	Paramter	Typ	Units
R <sub>θJC</sub>	Junction-to-Case	1.5	°C /W

**Package Information****TO-220F PACKAGE**

	单位: mm		
	MIN	NOM	MAX
A	4.35	4.55	4.75
A 1	2.3	2.5	2.7
A 2	0.4	0.6	0.8
A 3	2.1	2.3	2.5
b	0.6	0.8	1.0
b 1	1.0	1.2	1.4
c	0.3	0.5	0.7
e	2.3	2.5	2.7
E	9.8	10	10.2
E 1	6.3	6.5	6.7
H	15.6	15.8	16.0
H 1	8.8	9	9.2
H 2	12.9	13.2	13.5
H 3	3.1	3.3	3.5
G	3.1	3.3	3.5
ΦP	3.1	3.3	3.5